

# **NCE N-Channel Super Trench Power MOSFET**

#### **Description**

The NCEP0225F uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS}(\text{ON})}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

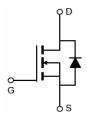
#### **General Features**

- $V_{DS}$  =200V, $I_D$  =25A  $R_{DS(ON)}$ =40m $\Omega$  (typical) @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating

### **Application**

- LED backlighting
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED!



#### Schematic diagram



Marking and pin assignment



TO-220F top view

**Package Marking and Ordering Information** 

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP0225F	NCEP0225F	TO-220F	-	-	-

### Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	200	V
Gate-Source Voltage	$V_{GS}$	±20	V
Drain Current-Continuous	I <sub>D</sub>	25	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	17.6	Α
Pulsed Drain Current	I <sub>DM</sub>	100	Α
Maximum Power Dissipation	$P_D$	45	W
Derating factor		0.3	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	320	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	$^{\circ}\mathbb{C}$

#### **Thermal Characteristic**



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# NCEP0225F

Thermal Résistance, Junction-to-Case<sup>(Note 2)</sup> R<sub>θJC</sub> 3.3 °C/W

Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	200	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.5	3.5	4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	40	50	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	15	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>	\/ -100\/\/ -0\/	-	1635		PF
Output Capacitance	Coss	$V_{DS}$ =100V, $V_{GS}$ =0V,	-	128		PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	3		PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	7	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =100 $V$ , $R$ L=7.5 $\Omega$	-	9	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$	-	25	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	5	-	nS
Total Gate Charge	Qg	\/ 400\/ L 00A	-	25	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =100V,I <sub>D</sub> =20A,	-	10.6	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	6	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	25	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = I_S$	-	45	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	160	-	nC

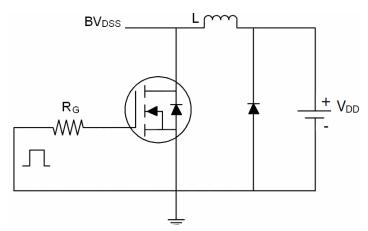
#### Notes:

- ${\it 1. Repetitive Rating: Pulse width limited by maximum junction temperature.}\\$
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}$ C,V<sub>DD</sub>=50V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

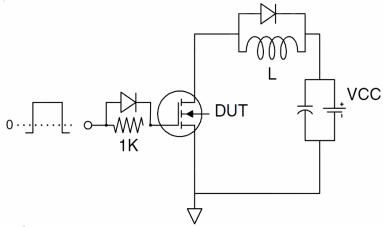


### **Test Circuit**

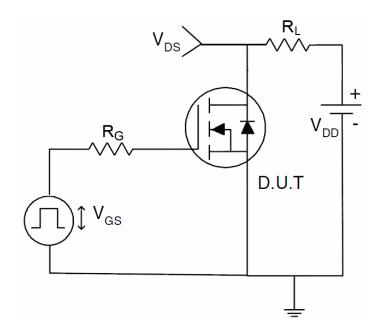
# 1) E<sub>AS</sub> test Circuit



# 2) Gate charge test Circuit

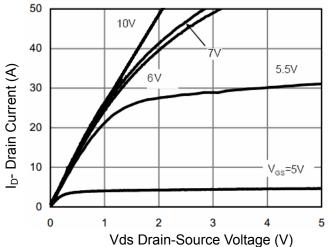


# 3) Switch Time Test Circuit

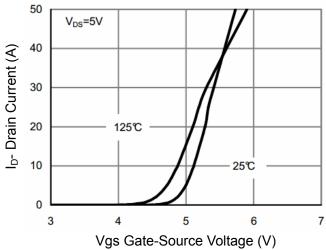




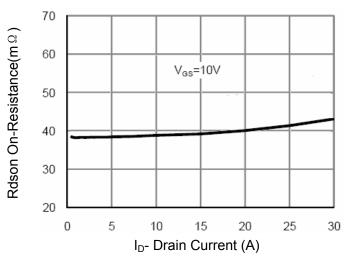




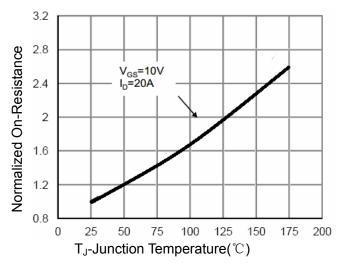
**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 



**Figure 3 Rdson- Drain Current** 



**Figure 4 Rdson-Junction Temperature** 

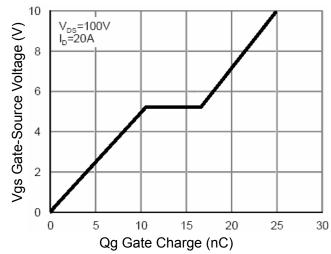


Figure 5 Gate Charge

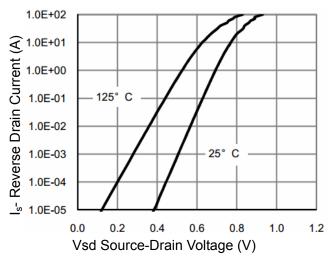


Figure 6 Source- Drain Diode Forward



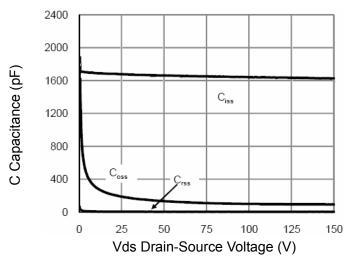


Figure 7 Capacitance vs Vds

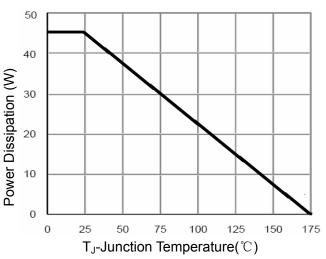


Figure 9 Power De-rating

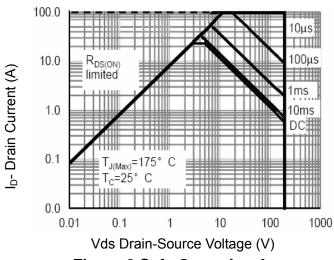


Figure 8 Safe Operation Area

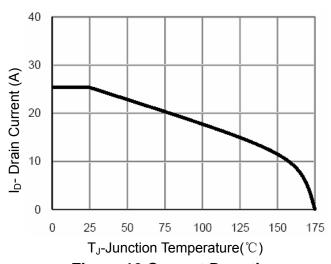
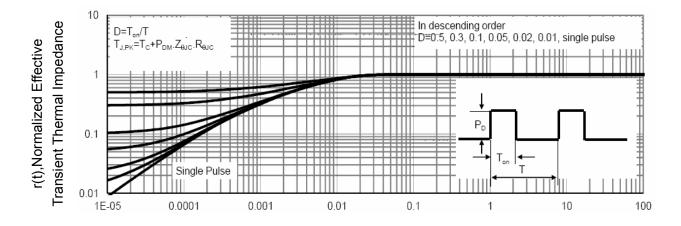


Figure 10 Current De-rating

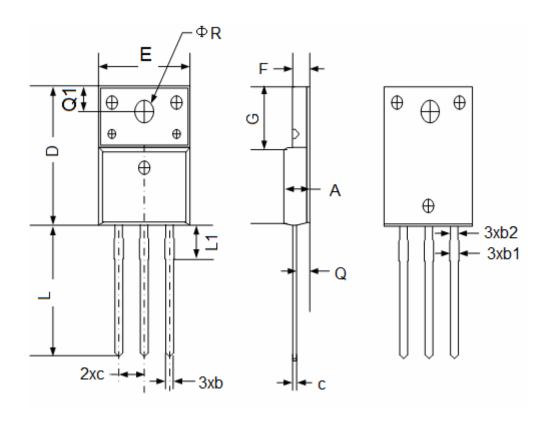


Square Wave Pluse Duration(sec)

**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **TO-220F Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	4.50	4.83	0.18	0. 19	
b	0.70	0.91	0.03	0.04	
b1	1.20	1.47	0.05	0.06	
b2	1.10	1.38	0.04	0.05	
С	0.45	0.63	0.02	0.02	
D	15.67	16.07	0.62	0. 63	
е	2.54 BSC		0.10 BSC		
E	9.96	10.36	0.39	0.41	
F	2.34	2.74	0.09	0. 11	
G	6.48	6.90	0. 26	0. 27	
L	12.68	13.30	0.50	0. 52	
L1	3.13	3.50	0.12	0. 14	
Q	2.56	2.93	0.10	0. 12	
Q1	3.20	3.40	0.13	0. 13	
ФК	3.08	3.28	0. 12	0. 13	

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# NCEP0225F

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